

BTA225B-800B 3Q Hi-Com Triac

Rev.04 - 03 January 2024

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a TO263 (D2PAK) surface mountable plastic package intended for use in circuits where high static and dynamic dV/dt and high dl/dt can occur. This "series B" triac will commutate the full rated RMS current at the maximum rated junction temperature without the aid of a snubber.

2. Features and benefits

- 3Q technology for improved noise immunity
- High blocking voltage capability
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- · Less sensitive gate for very high noise immunity
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Triggering in three quadrants only

3. Applications

- Heating controls
- High power motor control
- High power switching

4. Quick reference data

| Table 1. Q | uick reference data | | | | | |
|---------------------|--|---|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V_{DRM} | repetitive peak off-state voltage | | - | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 91 °C; <u>Fig. 1; Fig. 2; Fig. 3</u> | - | - | 25 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 190 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | - | 209 | А |
| Tj | junction temperature | | - | - | 125 | °C |
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static ch | aracteristics | | | | | |
| I _{GT} | gate trigger current | $V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$ | 2 | 18 | 50 | mA |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|--|------|------|------|------|
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 7</u> | 2 | 21 | 50 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u> | 2 | 34 | 50 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 31 | 60 | mA |
| V _T | on-state voltage | I _T = 30 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1,3 | 1.55 | V |
| Dynamic | characteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 536 \text{ V}; \text{ T}_{\text{j}} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit | 1000 | 4000 | - | V/µs |
| dI _{com} /dt | rate of change of commutating current | $\label{eq:V_D} \begin{array}{l} V_{\text{D}} = 400 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{\text{T(RMS)}} = 25 \text{ A}; \\ \text{d}\text{V}_{\text{com}}/\text{d}t = 20 \text{ V}/\mu\text{s}; \text{ gate open circuit}; \\ \hline \text{Fig. } 12 \end{array}$ | - | 44 | - | A/ms |

5. Pinning information

| Table 2. P | Table 2. Pinning information | | | | | | | | |
|------------|------------------------------|--------------------------------|--------------------|----------------|--|--|--|--|--|
| Pin | Symbol | Description | Simplified outline | Graphic symbol | | | | | |
| 1 | T1 | main terminal 1 | | | | | | | |
| 2 | T2 | main terminal 2 | | T2-T1 | | | | | |
| 3 | G | gate | └┘ └┘ | K _G | | | | | |
| mb | T2 | mounting base; main terminal 2 | | sym051 | | | | | |

6. Ordering information

| Table 3. Ordering information | | | | | | | | | |
|-------------------------------|-----------------|-----------------------|----------------|---------------------------|-----------------|-----------------------|--|--|--|
| Type number | Package Name | Orderable part number | Packing method | Small packing quantity | Package version | Package issue date | | | |
| BTA225B-800B | TO263 | BTA225B-800B,118 | Reel | 800 | TO263N (N) | 26-Sep-2016 | | | |
| | | | | | TO263P (P) | 12-Jun-2023 | | | |

7. Marking

| Table 4. Marking codes | | |
|------------------------|---------------------|---------------------|
| Type number | Marking codes | |
| | Assembly factory: N | Assembly factory: P |
| BTA225B-800B | BTA225B 800B | BTA225B 800B |
| | PJNxxxx xx | PJPxxxx xx |

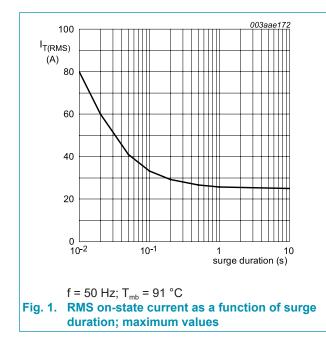
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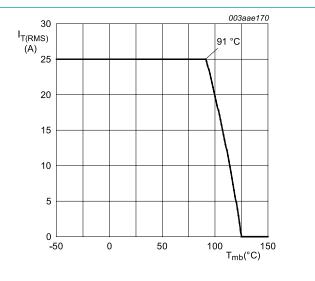
8. Limiting values

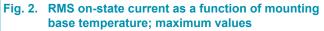
Table 5. Limiting values

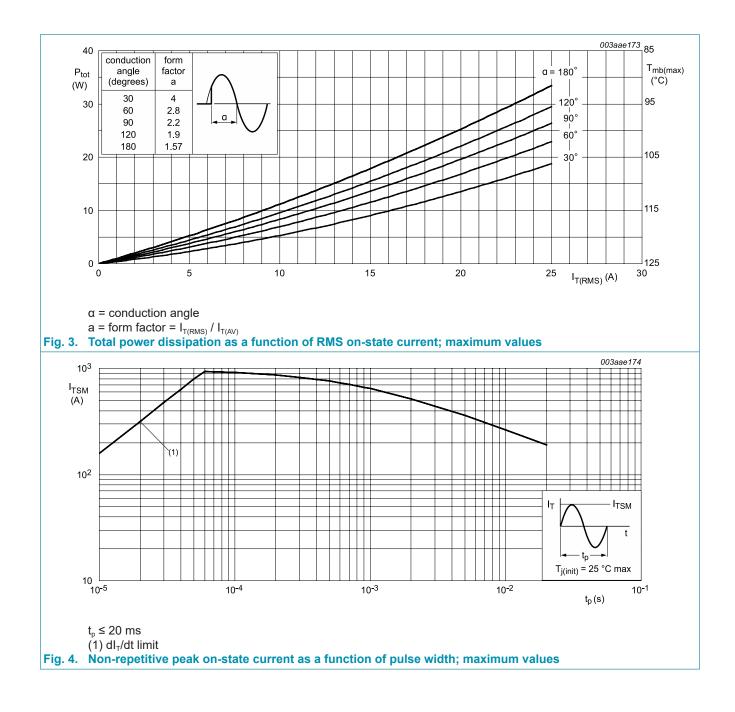
In accordance with the Absolute Maximum Rating System (IEC 60134).

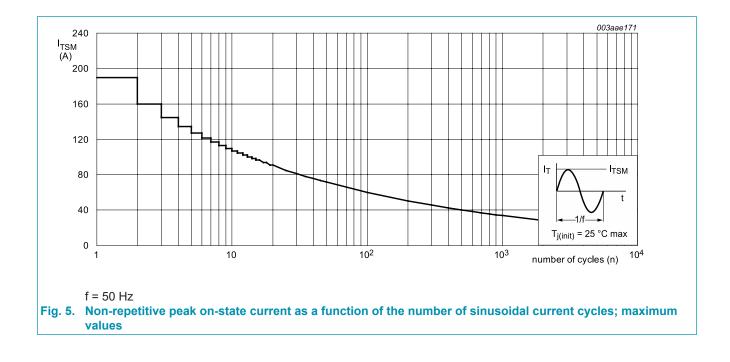
| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|---|---|-----|-----|------------------|
| V_{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 91 °C; <u>Fig. 1; Fig. 2; Fig. 3</u> | - | 25 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig 4; Fig 5 | - | 190 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 209 | А |
| l ² t | l ² t for fusing | t _P = 10 ms; SIN | - | 180 | A ² s |
| dl⊤/dt | rate of rise of on-state current | I _G = 100 mA | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | A |
| P_{GM} | peak gate power | | - | 5 | W |
| $P_{G(AV)}$ | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| T _j | junction temperature | | - | 125 | °C |





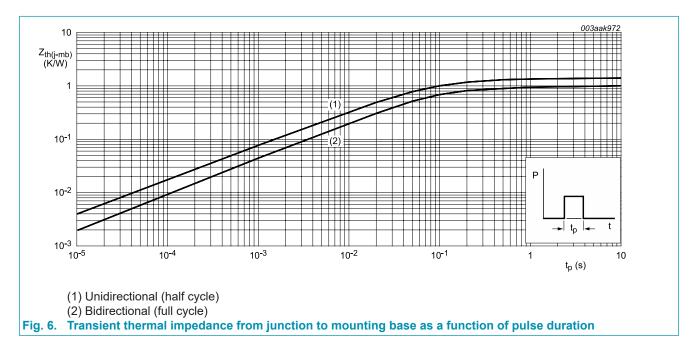






9. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|-------------------------------------|-----|-----|-----|------|
| $R_{th(j-mb)}$ | thermal resistance | full cycle; <u>Fig. 6</u> | - | - | 1 | K/W |
| | from junction to mounting base | half cycle; <u>Fig. 6</u> | - | - | 1.4 | K/W |
| $R_{\text{th(j-a)}}$ | thermal resistance from junction to ambient free air | printed circuit board (FR4) mounted | - | 55 | - | K/W |

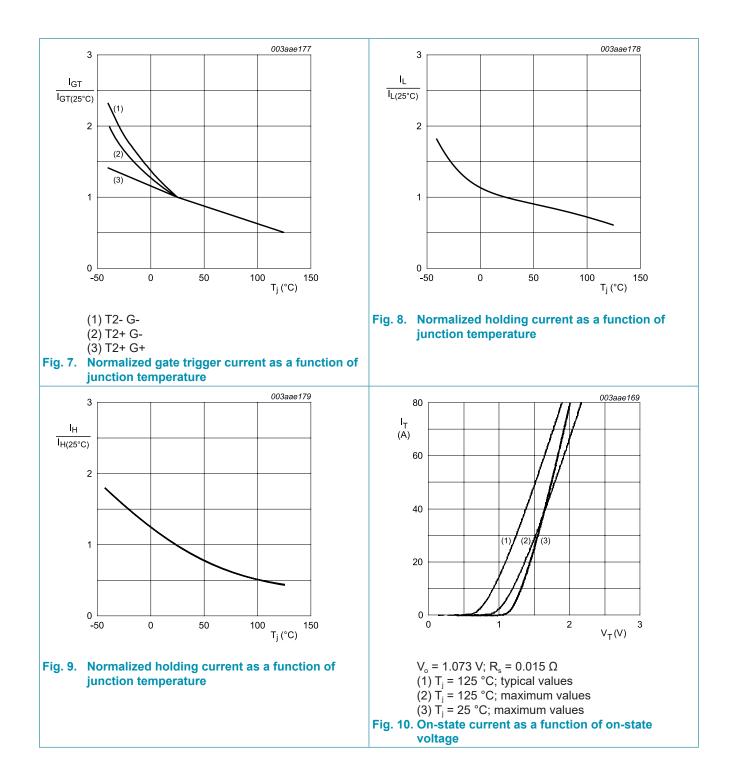


10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit | |
|-----------------------|---------------------------------------|--|---|------|------|------|----|
| Static cha | racteristics | | | | | | |
| I _{GT} | gate trigger current | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$ | 2 | 18 | 50 | mA | |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 7</u> | 2 | 21 | 50 | mA | |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 7</u> | 2 | 34 | 50 | mA | |
| IL | latching current | $V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 8}$ | - | 31 | 60 | mA | |
| | | | $V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 34 | 90 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 30 | 60 | mA | |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 31 | 60 | mA | |
| V _T | on-state voltage | $I_{T} = 30 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$ | - | 1,3 | 1.55 | V | |
| $V_{\rm GT}$ | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V | |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; <u>Fig. 11</u> | 0.25 | 0.4 | - | V | |
| I _D | off-state current | V _D = 800 V; T _j = 125 °C | - | 0.1 | 0.5 | mA | |
| Dynamic | characteristics | | | • | | | |
| dV _D /dt | rate of rise of off-state voltage | tate $V_{DM} = 536 \text{ V}; T_j = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit | | 4000 | - | V/µs | |
| dI _{com} /dt | rate of change of commutating current | $V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 25 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu s;$ gate open circuit; Fig. 12 | - | 44 | - | A/ms | |

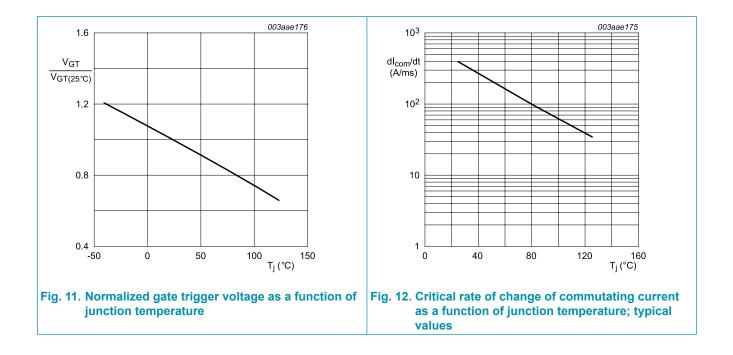
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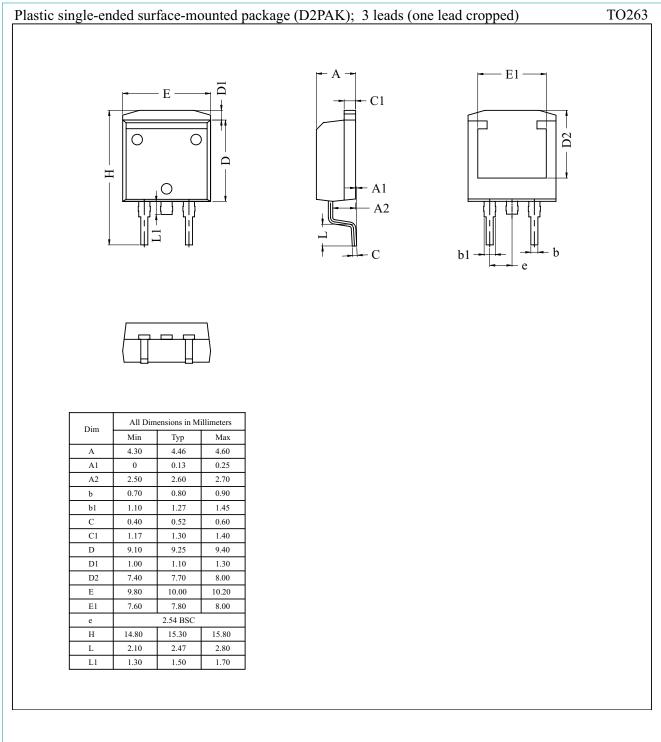


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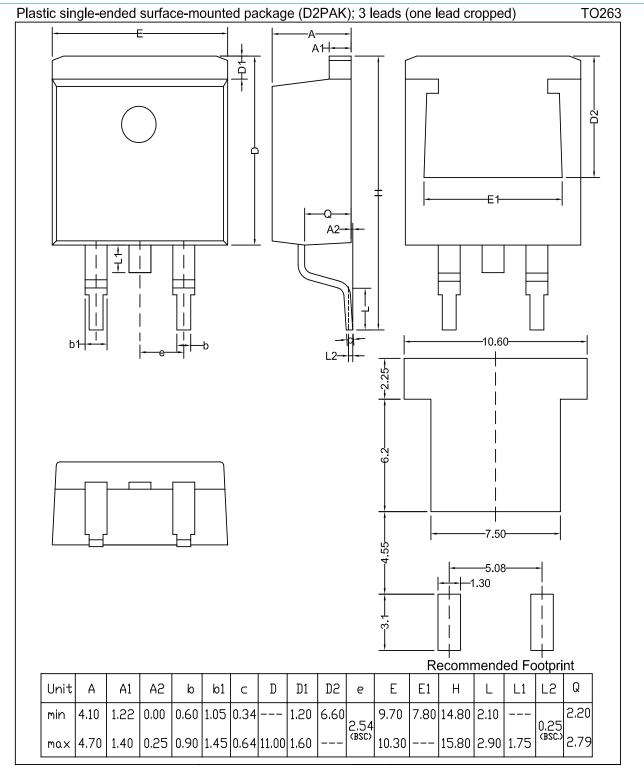
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Assembly factory: P



Assembly factory: N



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Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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- [2] The term 'short data sheet' is explained in section "Definitions".
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For sales office addresses, please send an email to:salesaddresses@ween-semi.com Date of release: 03 January 2024